(Unit: mm)

PC817 Series

High Density Mounting Type Photocoupler

Lead forming type (I type) and taping reel type (P type) are also available. (PC817I/PC817P)
 TÜV (VDE0884) approved type is also available as an option.

■ Features

1. Current transfer ratio

(CTR: MIN. 50% at $I_F = 5mA$, $V_{CE}=5V$)

2. High isolation voltage between input and

output (V_{iso} : 5 000 V_{rms})

3. Compact dual-in-line package

PC817: 1-channel type PC827: 2-channel type PC837: 3-channel type PC847: 4-channel type

4. Recognized by UL, file No. E64380

■ Applications

- 1. Computer terminals
- 2. System appliances, measuring instruments
- Registers, copiers, automatic vending machines
- 4. Electric home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

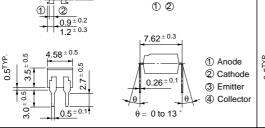
 2.54 ± 0.25

PC8,

PC817

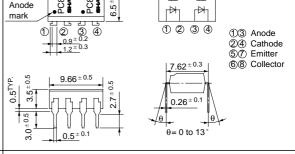
rank mark

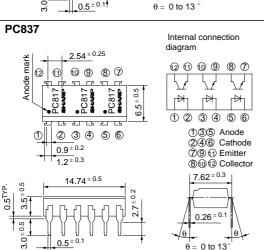
Anode mark

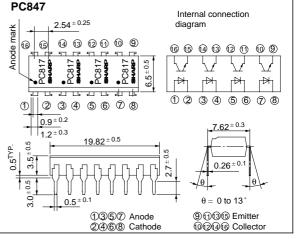


Internal connection diagram

4) 3)







■ Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

	Parameter	Symbol	Symbol Rating		
Input	Forward current	I_F	50	mA	
	*1Peak forward current	I _{FM}	1	A	
	Reverse voltage	V _R	6	V	
	Power dissipation	P	70	mW	
Output	Collector-emitter voltage	V _{CEO}	35	V	
	Emitter-collector voltage	V ECO	6	V	
	Collector current	Ic	50	mA	
	Collector power dissipation	Pc	150	mW	
	Total power dissipation	P tot	200	mW	
*2Isolation voltage		V iso	5 000	V _{rms}	
Operating temperature		T opr	- 30 to + 100	°C	
	Storage temperature	T stg	- 55 to + 125	°C	
	*3Soldering temperature	T sol	260	°C	

^{*1} Pulse width \leq =100 μ s, Duty ratio: 0.001

■ Electro-optical Characteristics

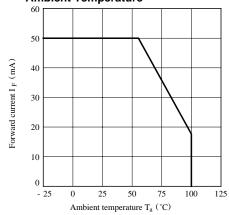
 $(Ta = 25^{\circ}C)$

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage		VF	$I_F = 20mA$	-	1.2	1.4	V
	Peak forward voltage		V _{FM}	$I_{FM} = 0.5A$	-	-	3.0	V
	Reverse current		I_R	$V_R = 4V$	-	-	10	μΑ
	Terminal capacitance		C_{t}	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark cur	rent	I_{CEO}	$V_{CE} = 20V$	-	-	10 -7	A
Transfer charac- teristics	*4Current transfer ratio		CTR	$I_F = 5 \text{mA}, V_{CE} = 5 \text{V}$	50	-	600	%
	Collector-emitter saturation voltage		V _{CE(sat)}	$I_F = 20$ mA, $I_C = 1$ mA	-	0.1	0.2	V
	Isolation resistance		R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	1011	-	Ω
	Floating capacitance		C_{f}	V = 0, $f = 1MHz$	-	0.6	1.0	pF
	Cut-off frequency		fc	$V_{CE} = 5V, I_{C} = 2mA, R_{L} = 100 \Omega, -3dB$	-	80	-	kHz
	Response time	Rise time	$t_{\rm r}$	$V_{CE} = 2V, I_{C} = 2mA, R_{L} = 100 \Omega$	-	4	18	μs
		Fall time	t_{f}		-	3	18	μs

^{*4} Classification table of current transfer ratio is shown below.

Model No.	Rank mark	CTR (%)
PC817A	A	80 to 160
PC817B	В	130 to 260
PC817C	C	200 to 400
PC817D	D	300 to 600
PC8*7AB	A or B	80 to 260
PC8*7BC	B or C	130 to 400
PC8 * 7CD	C or D	200 to 600
PC8 ** 7AC	A, B or C	80 to 400
PC8 ** 7BD	B, C or D	130 to 600
PC8 * 7AD	A, B, C or D	80 to 600
PC8 ** 7	A, B, C, D or No mark	50 to 600

Fig. 1 Forward Current vs. Ambient Temperature



^{*2 40} to 60% RH, AC for 1 minute

^{*3} For 10 seconds

Fig. 2 Collector Power Dissipation vs.
Ambient Temperature

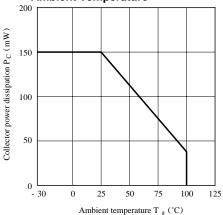


Fig. 4 Current Transfer Ratio vs. Forward Current

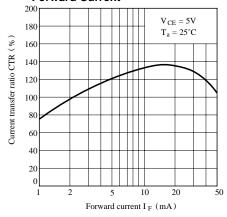


Fig. 6 Collector Current vs.
Collector-emitter Voltage

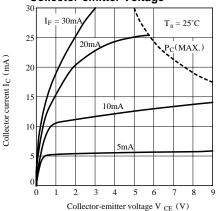


Fig. 3 Peak Forward Current vs. Duty Ratio

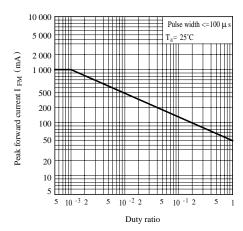


Fig. 5 Forward Current vs. Forward Voltage

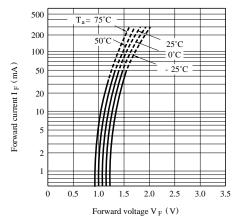


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

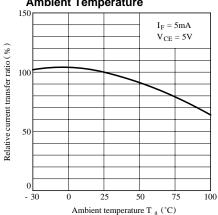


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

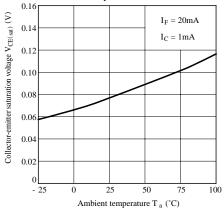
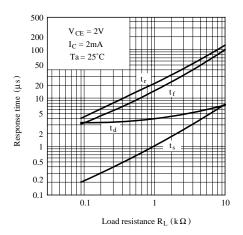
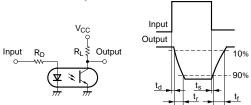


Fig.10 Response Time vs. Load Resistance



Test Circuit for Response Time



Test Circuit for Frepuency Response

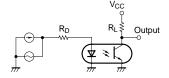


Fig. 9 Collector Dark Current vs.
Ambient Temperature

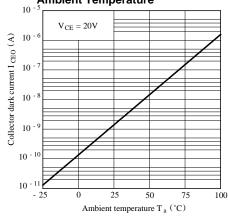


Fig.11 Frequency Response

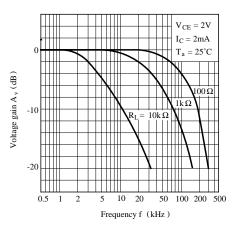
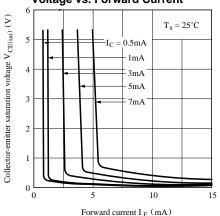


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Please refer to the chapter "Precautions for Use"

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www.datasheetcatalog.com

Datasheets for electronics components.